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## INFORMATION DISCLOSURE STATEMENT BY APPLICANT

*(Use as many sheets as necessary)*

Sheet

1

of

2

Application Number

09/867.662

Filing Date

31 May 2001

First Named Inventor

**LUC OUELLET**

Art Unit
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1762

Examiner Name

Attorney Docket Number

11471-US
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## U. S. PATENT DOCUMENTS

[illegible]

## FOREIGN PATENT DOCUMENTS

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. <sup>1</sup>	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T <sup>6</sup>
		Country Code <sup>3</sup> Number <sup>4</sup> Kind Code <sup>5</sup> (if known)				
BT		EP 1 134 073 A1	09-19-2001			
BT		EP 0 788 148 A1	08-06-1997			

Examiner Signature	B. Talbot	Date Considered	10/28/04
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**INFORMATION DISCLOSURE  
STATEMENT BY APPLICANT**

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Sheet

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of

2

Application Number

Complete if Known

09/867,662

Filing Date

31 May 2001

First Named Inventor

Luc OUELLET

Art Unit

1762

Examiner Name

Attorney Docket Number

11471-US

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TC 1700**NON PATENT LITERATURE DOCUMENTS**

Examiner Initials*	Cite No. <sup>1</sup>	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>2</sup>
BT		KIM, Kihong, et al., "Properties of low dielectric constant fluorinated silicon oxide films prepared by plasma enhanced chemical vapor deposition", Thin Solid Films, 1998, Vol. 332, No. 1/2, pages 369-374.	
BT		TAKAMATSU, Akira et al., "Plasma-activated deposition and properties of phosphosilicate glass film", Journal of Electrochemical Society, 1984, Vol. 131, No. 8, pages 1865-1870.	

Examiner  
Signature

B. Talbot

Date

Considered

10/23/04

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